2.5 V/3.3 V ECL 2-Input Differential AND/NAND

MC100LVEP05

Description

The MC100LVEP05 is a 2-input differential AND/NAND gate. The MC100LVEP05 is the low voltage version of the MC100EP05 and is functionally equivalent to the EL05 and LVEL05 devices. With AC performance much faster than the LVEL05 device, the MC100LVEP05 is ideal for low voltage applications requiring the fastest AC performance available.

The 100 Series contains temperature compensation.

Features

- 220 ps Typical Propagation Delay
- Input Clock Frequency > 3 GHz
- 0.2 ps Typical RMS Random Clock Period Jitter
- LVPECL Mode Operating Range: V_{CC} = 2.375 V to 3.6 V with V_{EE} = 0 V
- NECL Mode Operating Range: V_{CC} = 0 V with V_{EE} = -2.375 V to -3.6 V
- Open Input Default State
- Q Output Will Default LOW with Inputs Open
- These Device are Pb-Free, Halogen Free and are RoHS Compliant



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TSSOP-8 DT SUFFIX CASE 948R DFN8 MN SUFFIX CASE 506AA

MARKING DIAGRAMS*





K = MC100

M = Date Code

A = Assembly Location

= Wafer Lot

Y = Year

W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)
*For additional marking information, refer to
Application Note AND8002/D.

ORDERING INFORMATION

Device	Package	Shipping [†]
MC100LVEP05DTG	TSSOP-8 (Pb-Free)	100 Units / Tube
MC100LVEP05DTR2G	TSSOP-8 (Pb-Free)	2500 / Tape & Reel
MC100LVEP05MNTXG	DFN8 (Pb-Free)	1000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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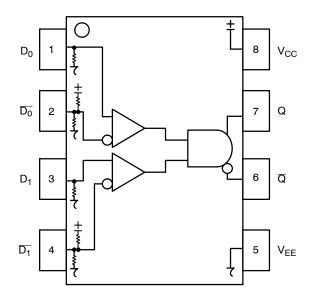


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram

Table 1. PIN DESCRIPTION

Pin	Function				
D0*, D1*, D0 **, D1 **	ECL Data Inputs				
Q, Q	ECL Data Outputs				
V _{CC}	Positive Supply				
V _{EE}	Negative Supply				
EP	(DFN8 only) Thermal exposed pad must be connected to a sufficient thermal conduit. Electrically connect to the most negative supply (GND) or leave unconnected, floating open.				

Table 2. TRUTH TABLE

D0	D1	D0	D1	Q	Q
L H H	⊔ H ⊔ H	ΗΗL	HLHL	LLII	HHH

Table 3. ATTRIBUTES

Characteristics	Value
Internal Input Pulldown Resistor	75 kΩ
Internal Input Pullup Resistor	37.5 kΩ
ESD Protection Human Body Model Machine Model Charged Device Model	> 4 kV > 200 V > 2 kV
Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1) TSSOP-8 DFN8	Pb-Free Pkg Level 3 Level 1
Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in
Transistor Count	167 Devices
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test	•

^{1.} For additional information, see Application Note AND8003/D.

 $^{^{\}star}$ Pins will default LOW when left open. ** Pins will default to VCC/2when left open.

Table 4. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		6	V
V _{EE}	NECL Mode Power Supply	V _{CC} = 0 V		-6	V
V _I	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	$V_{I} \leq V_{CC}$ $V_{I} \geq V_{EE}$	6 -6	V V
l _{out}	Output Current	Continuous Surge		50 100	mA mA
T _A	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	TSSOP-8 TSSOP-8	185 140	°C/W
θ _{JC}	Thermal Resistance (Junction-to-Case)	Standard Board	TSSOP-8	41 to 44	°C/W
$\theta_{\sf JA}$	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	DFN8 DFN8	129 84	°C/W
θJC	Thermal Resistance (Junction-to-Case)	(Note 2)	DFN8	35 to 40	°C/W
T _{sol}	Wave Solder	3 sec @ 260°C		265	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. JEDEC standard multilayer board – 2S2P (2 signal, 2 power)

Table 5. 100EP DC CHARACTERISTICS, PECL V_{CC} = 2.5 V, V_{EE} = 0 V (Note 3)

			–40°C		25°C		85°C					
Symbol	Characteristic		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		15	25	32	17	27	36	19	28	38	mA
V _{OH}	Output HIGH Voltage (Note 4)		1355	1480	1605	1355	1480	1605	1355	1480	1605	mV
V _{OL}	Output LOW Voltage (Note 4)		555	730	900	555	730	900	555	730	900	mV
V _{IH}	Input HIGH Voltage (Single-Ended)		1355		1620	1355		1620	1355		1620	mV
V _{IL}	Input LOW Voltage (Single-Ended)		555		900	555		900	555		900	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Notes 5, 6)		1.2		2.5	1.2		2.5	1.2		2.5	V
I _{IH}	Input HIGH Current				150			150			150	μΑ
I _{IL}	Input LOW Current	$\frac{D}{D}$	0.5 -150			0.5 -150			0.5 -150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

- 3. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.125 V to -1.3 V.

- Input and output parameters vary 1.1 with V_{CC}. V_{EE} can vary +0.125 V to −1.3 V.
 All loading with 50 Ω to V_{CC} − 2.0 V.
 Single-ended input CLK pin operation is limited to V_{CC} ≥ 3.0 V in PECL mode.
 V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

Table 6. 100EP DC CHARACTERISTICS, PECL V_{CC} = 3.3 V, V_{EE} = 0 V (Note 7)

			-40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	15	25	32	17	27	36	19	28	38	mA
V _{OH}	Output HIGH Voltage (Note 8)	2155	2280	2405	2155	2280	2405	2155	2280	2405	mV
V _{OL}	Output LOW Voltage (Note 8)	1355	1530	1700	1355	1530	1700	1355	1530	1700	mV
V _{IH}	Input HIGH Voltage (Single-Ended)	2075		2420	2075		2420	2075		2420	mV
V _{IL}	Input LOW Voltage (Single-Ended)	1355		1675	1355		1675	1355		1675	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 9)	1.2		3.3	1.2		3.3	1.2		3.3	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current [0.5 -150			0.5 -150			0.5 -150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

- 7. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.3 V to -2.2 V. 8. All loading with 50 Ω to V_{CC} 2.0 V.
- 9. VIHCMR min varies 1:1 with VEE, VIHCMR max varies 1:1 with VCC. The VIHCMR range is referenced to the most positive side of the differential input signal.

Table 7. 100EP DC CHARACTERISTICS, NECL $V_{CC} = 0 \text{ V}$, $V_{EE} = -2.375 \text{ V}$ to -3.6 V (Note 10)

			-40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	15	25	32	17	27	36	19	28	38	mA
V _{OH}	Output HIGH Voltage (Note 11)	-1145	-1020	-895	-1145	-1020	-895	-1145	-1020	-895	mV
V _{OL}	Output LOW Voltage (Note 11)	-1945	-1770	-1600	-1945	-1770	-1600	-1945	-1770	-1600	mV
V _{IH}	Input HIGH Voltage (Single-Ended)	-1165		-880	-1165		-880	-1165		-880	mV
V _{IL}	Input LOW Voltage (Single-Ended)	-1945		-1600	-1945		-1600	-1945		-1600	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 12)	V _{EE}	+1.2	0.0	V _{EE}	+1.2	0.0	V _{EE}	+1.2	0.0	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current D	0.5 -150			0.5 -150			0.5 -150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

 ^{10.} Input and output parameters vary 1:1 with V_{CC}.
 11. All loading with 50 Ω to V_{CC} – 2.0 V.
 12. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

Table 8. AC CHARACTERISTICS $V_{CC} = 0 \text{ V}; V_{EE} = -2.375 \text{ V to } -3.6 \text{ V or } V_{CC} = 2.375 \text{ V to } 3.6 \text{ V}; V_{EE} = 0 \text{ V (Note 13)}$

		-40°C		25°C		85°C					
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{max}	Maximum Frequency (Figure 2)	3.0			3.0			3.0			GHz
t _{PLH} , t _{PHL}	Propagation Delay to Output Differential	160	210	260	170	220	270	210	260	320	ps
tuitter	RMS Random Clock Jitter $f_{in} \le 3.0 \text{ GHz}$ (Figure 2)		0.2	1		0.2	1		0.2	1.5	ps
V _{PP}	Input Voltage Swing (Differential Configuration)	150	800	1200	150	800	1200	150	800	1200	mV
t _r	Output Rise/Fall Times Q (20% – 80%)	70	120	170	80	130	180	100	150	200	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

13. Measured using a 750 mV source, 50% duty cycle clock source. All loading with 50 Ω to V_{CC} – 2.0 V.

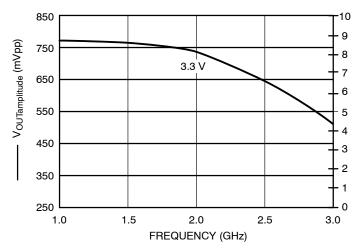


Figure 2. F_{max} @ 25°C

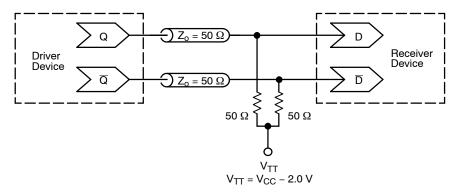


Figure 3. Typical Termination for Output Driver and Device Evaluation (See Application Note <u>AND8020/D</u> – Termination of ECL Logic Devices.)

Resource Reference of Application Notes

AN1405/D - ECL Clock Distribution Techniques

AN1406/D - Designing with PECL (ECL at +5.0 V)

AN1503/D - ECLinPS™ I/O SPiCE Modeling Kit

AN1504/D - Metastability and the ECLinPS Family

AN1568/D - Interfacing Between LVDS and ECL

AND8001/D - The ECL Translator Guide

AND8001/D - Odd Number Counters Design

AND8002/D - Marking and Date Codes

 $\textbf{AND8020/D} \quad - \quad \text{Termination of ECL Logic Devices}$

AND8066/D - Interfacing with ECLinPS

AND8090/D - AC Characteristics of ECL Devices

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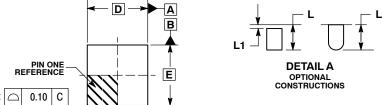


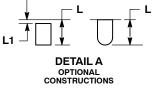


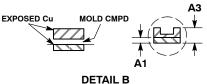
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DFN8 2x2, 0.5P CASE 506AA **ISSUE F**

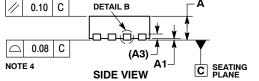
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ALTERNATE CONSTRUCTIONS



TOP VIEW



NOTES

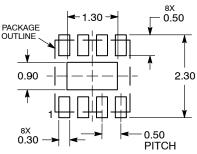
0.70 0.90 0.50 BSC K 0.30 REF 0.35

DIMENSIONING AND TOLERANCING PER

PAD AS WELL AS THE TERMINALS.

ASME Y14.5M, 1994 . CONTROLLING DIMENSION: MILLIMETERS. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP. COPLANARITY APPLIES TO THE EXPOSED

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

DETAIL A ←D2 → 0.10 CAB е С 0.05 NOTE 3 **BOTTOM VIEW**

GENERIC MARKING DIAGRAM*



XX = Specific Device Code

= Date Code

= Pb-Free Device

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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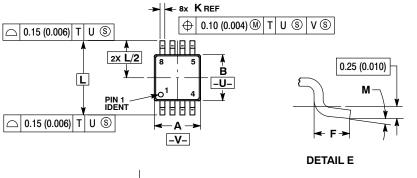
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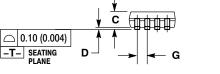
^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

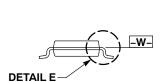


TSSOP 8 CASE 948R-02 ISSUE A

DATE 04/07/2000







- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH. OR GATE BURRS SHALL NOT EXCEED 0.15
- (0.006) PER SIDE.
 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 5. TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.
 6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	2.90	3.10	0.114	0.122	
В	2.90	3.10	0.114	0.122	
С	0.80	1.10	0.031	0.043	
D	0.05	0.15	0.002	0.006	
F	0.40	0.70	0.016	0.028	
G	0.65	BSC	0.026	BSC	
K	0.25	0.40	0.010	0.016	
L	4.90	BSC	0.193 BSC		
M	٥°	6 °	٥°	6°	

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